# NSN 5961-01-183-6502

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	Material
Inclosure	material:

Metal

**Overall Length:** 

0.150 inches

# Terminal Length:

0.500 inches

## **Overall Diameter:**

0.230 inches

## Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-52

## **Mounting Method:**

Terminal

## Terminal Circle Diameter:

0.100 inches

## **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

15.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 4.5 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

50.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

300.0 milliwatts small-signal input power, common-collector preset

## **Transfer Ratio:**

120.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: pnp

# **Terminal Type And Quantity:**

3 uninsulated wire lead

# Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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